TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

MT6L53E

VHF-UHF Band Low Noise Amplifier Application VHF-UHF Band Oscillator Application

 Tow devices are built in to the super-thin and ultra super mini (6 pin) package: ES6

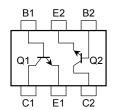
	Q1: SSM (TESM)	Q2: TESM
Three pin (SSM/TESM) type part No.	MT3S06S (MT3S06T)	MT3S05T

Maximum Ratings (Ta = 25°C)

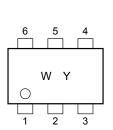
Characteristics	Symbol	Q1	Q2	Unit
Collector-base voltage	V_{CBO}	10	10	V
Collector-emitter voltage	V _{CEO}	5	5	V
Emitter-base voltage	V _{EBO}	1.5	2	V
Collector current	IC	15	40	mA
Base current	ΙB	7	10	mA
Collector power dissipation	P _C (Note 1)	100		mW
Junction temperature	Tj	125		°C
Storage temperature range	T _{stg}	-55 to 125		°C

Note 1: Total power dissipation of Q1 and Q2

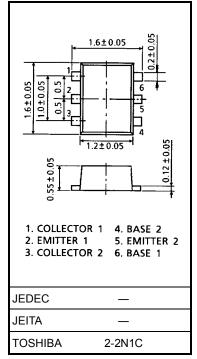
Marking



Pin Assignment



Unit: mm



Weight: 0.003 g (typ.)

Electrical Characteristics Q1-Side (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = 5 \text{ V}, I_{E} = 0$	_	_	0.1	μА
Emitter cut-off current	I _{EBO}	$V_{EB} = 1 \text{ V, } I_C = 0$	_	_	1	μА
DC current gain	h _{FE}	$V_{CE} = 1 \text{ V}, I_{C} = 5 \text{ mA}$	70	_	140	_
Transition frequency	f _T	$V_{CE} = 3 \text{ V}, I_{C} = 5 \text{ mA}$	7	10	_	GHz
Insertion gain —	S _{21e} ² (1)	$V_{CE} = 1 \text{ V}, I_{C} = 5 \text{ mA}, f = 2 \text{ GHz}$	_	7.5	_	dB
	S _{21e} ² (2)	$V_{CE} = 3 \text{ V}, I_{C} = 7 \text{ mA}, f = 2 \text{ GHz}$	4.5	8	_	
Noise figure	NF (1)	$V_{CE} = 1 \text{ V}, I_{C} = 3 \text{ mA}, f = 2 \text{ GHz}$	_	1.7	3	- dB
	NF (2)	$V_{CE} = 3 \text{ V}, I_{C} = 3 \text{ mA}, f = 2 \text{ GHz}$	_	1.6	3	
Reverse transfer capacitance	C _{re}	$V_{CB} = 1 \text{ V}, I_E = 0, f = 1 \text{ MHz}$	_	0.35	0.75	pF

Electrical Characteristics Q2-Side (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = 5 \text{ V}, I_{E} = 0$	_	_	0.1	μΑ
Emitter cut-off current	I _{EBO}	V _{EB} = 1 V, I _C = 0	_	_	1	μА
DC current gain	h _{FE}	$V_{CE} = 1 \text{ V, } I_{C} = 5 \text{ mA}$	80	_	140	_
Transition frequency	f _T	V _{CE} = 1 V, I _C = 5 mA	2	4.5	_	GHz
Insertion gain	S _{21e} ² (1)	$V_{CE} = 1 \text{ V}, I_{C} = 5 \text{ mA}, f = 1 \text{ GHz}$	_	7.5	_	dB
	S _{21e} ² (2)	$V_{CE} = 3 \text{ V}, I_{C} = 20 \text{ mA}, f = 1 \text{ GHz}$	7.5	10.5	_	ub
Noise figure	NF	$V_{CE} = 1 \text{ V}, I_{C} = 5 \text{ mA}, f = 1 \text{ GHz}$	_	1.4	2.2	dB
Reverse transfer capacitance	C _{re}	$V_{CB} = 1 \text{ V}, I_E = 0, f = 1 \text{ MHz}$	_	0.95	1.15	pF

Caution

This device electrostatic sensitivity. Please handle with caution.

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